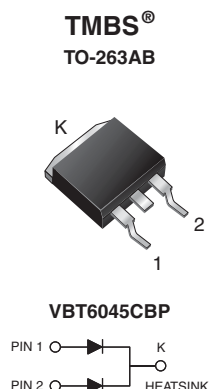


Trench MOS Barrier Schottky Rectifier for PV Solar Cell Bypass Protection

Ultra Low $V_F = 0.33 \text{ V}$ at $I_F = 10 \text{ A}$



FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- T_J 200 °C max. in solar bypass mode application
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT

TYPICAL APPLICATIONS

For use in solar cell junction box as a bypass diode for protection, using DC forward current without reverse bias.

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	2 x 30 A
V_{RRM}	45 V
I_{FSM}	320 A
V_F at $I_F = 30 \text{ A}$	0.47 V
T_{OP} max. (AC mode)	150 °C
T_J max. (DC forward current)	200 °C
Package	TO-263AB
Diode variation	Common cathode

MECHANICAL DATA

Case: TO-263AB

Molding compound meets UL 94 V-0 flammability rating
Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	VB T6045CBP	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	45	V
Maximum average forward rectified current (fig. 1)	$I_{F(AV)}$ ⁽¹⁾	60	A
		30	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	320	A
Operating junction and storage temperature range (AC mode)	T_{OP}, T_{STG}	-40 to +150	°C
Junction temperature in DC forward current without reverse bias, $t \leq 1 \text{ h}$	T_J ⁽²⁾	≤ 200	°C

Notes

⁽¹⁾ With heatsink

⁽²⁾ Meets the requirements of IEC 61215 ed. 2 bypass diode thermal test

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I _F = 10 A	T _A = 25 °C	V _F ⁽¹⁾	0.44	-	V
	I _F = 15 A			0.47	-	
	I _F = 30 A			0.54	0.64	
	I _F = 10 A	T _A = 125 °C		0.33	-	
	I _F = 15 A			0.37	-	
	I _F = 30 A			0.47	0.56	
Reverse current per diode	V _R = 45 V	T _A = 25 °C	I _R ⁽²⁾	-	3000	μA
		T _A = 125 °C		18	50	mA

Notes

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width $\leq 40\text{ ms}$

THERMAL CHARACTERISTICS ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)				
PARAMETER		SYMBOL	VB T6045CBP	UNIT
Typical thermal resistance	per diode	$R_{\theta JC}$	1.5	$^{\circ}\text{C/W}$
	per device		0.8	

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-263AB	VB T6045CBP-E3/4W	1.38	4W	50/tube	Tube
TO-263AB	VB T6045CBP-E3/8W	1.38	8W	800/reel	Tape and reel

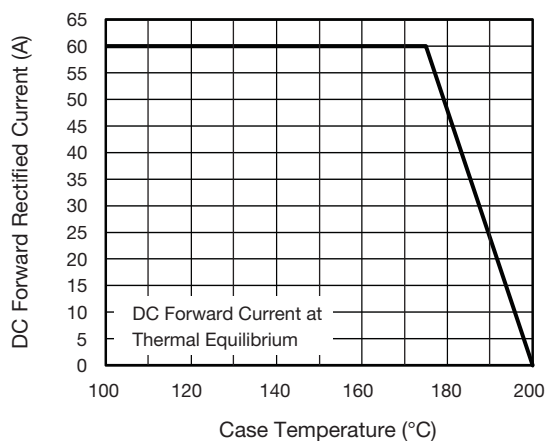
RATINGS AND CHARACTERISTICS CURVES ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)


Fig. 1 - Maximum Forward Current Derating Curve

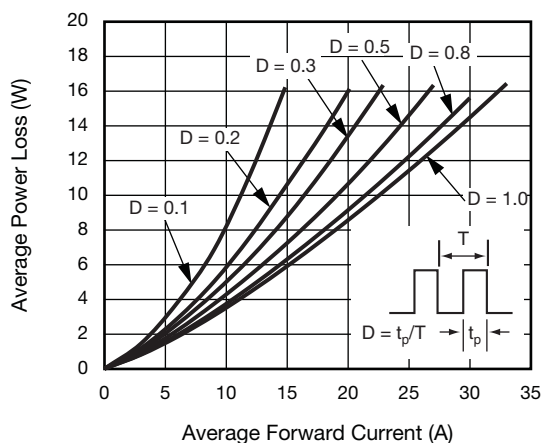


Fig. 2 - Forward Power Loss Characteristics Per Diode

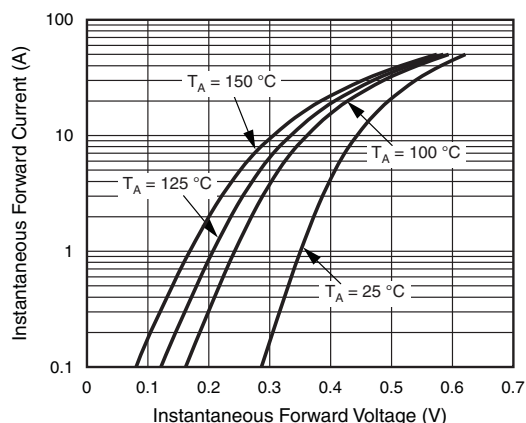


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

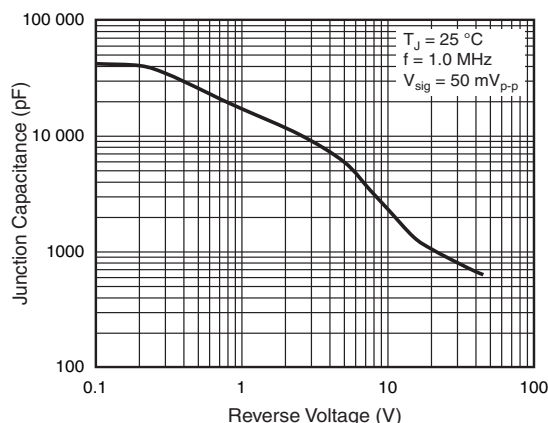


Fig. 5 - Typical Junction Capacitance Per Diode

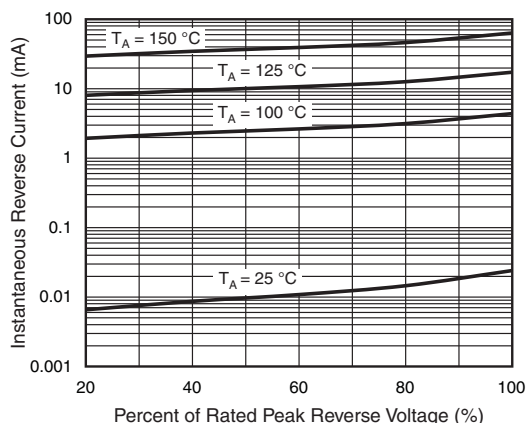


Fig. 4 - Typical Reverse Characteristics Per Diode

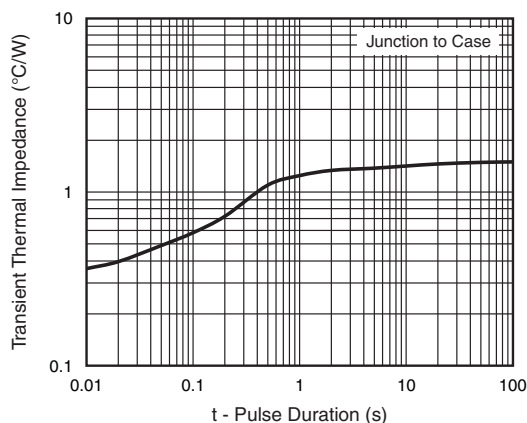


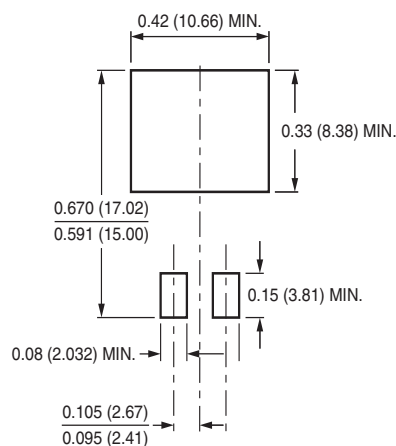
Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-263AB



Mounting Pad Layout





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